



#### 75V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

#### Description

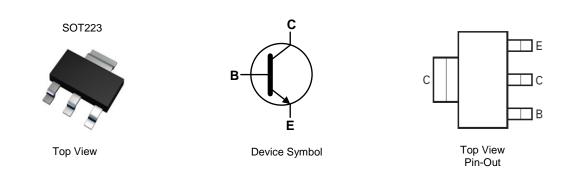
This bipolar junction transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

#### Features

- BV<sub>CEO</sub> > 75V
- I<sub>C</sub>= 4.5A High Continuous Collector Current
- I<sub>CM</sub> = 10A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 120mV @ 1A</li>
- hFE > 300 @ Ic=1A for a High Gain Hold-Up
- R<sub>CE(sat)</sub> = 78mΩ at 4.5A for a Low Equivalent On-Resistance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



#### Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT1053AQTA	Automotive	FZT1053A	7	12	1,000

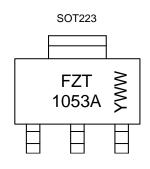
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



FZT1053A = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 9 = 2019) WW or  $\overline{W}W$  = Week Code (01 to 53)



#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	75	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	lc	4.5	А
Continuous Base Current	IB	500	mA
Peak Pulse Collector Current	I <sub>CM</sub>	10	А

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	(Note 6)		3.0		
Power Dissipation	(Note 7)		2.0	w	
	(Note 8)	PD	1.6	vv	
	(Note 9)		1.2		
	(Note 6)		41.7		
Thermal Resistance, Junction to Ambient	(Note 7)	D	62.5		
	(Note 8)	R <sub>0JA</sub>	78.1	°C/W	
	(Note 9)		104		
Thermal Resistance Junction to Lead	(Note 10)	$R_{ ext{ heta}JL}$	10.9		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

### ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

8. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

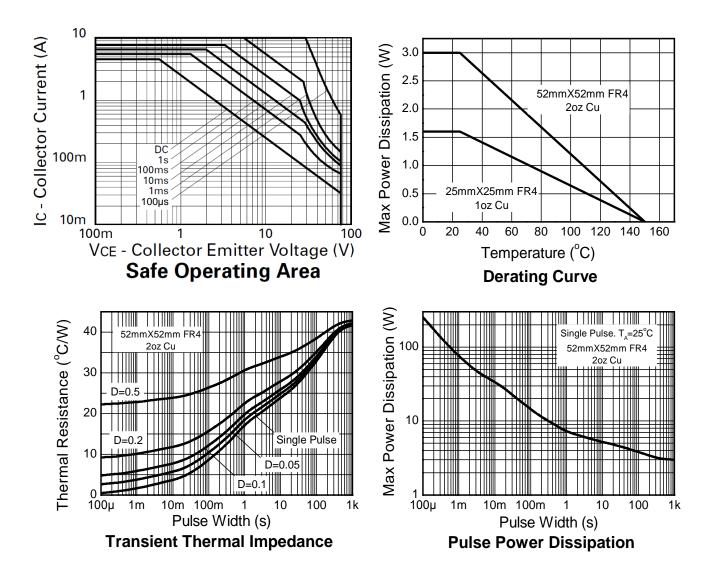
9. Same as Note 6, except the device is mounted on minimum recommended pad layout.

10. Thermal resistance from junction to solder-point (at the end of the collector lead).

11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





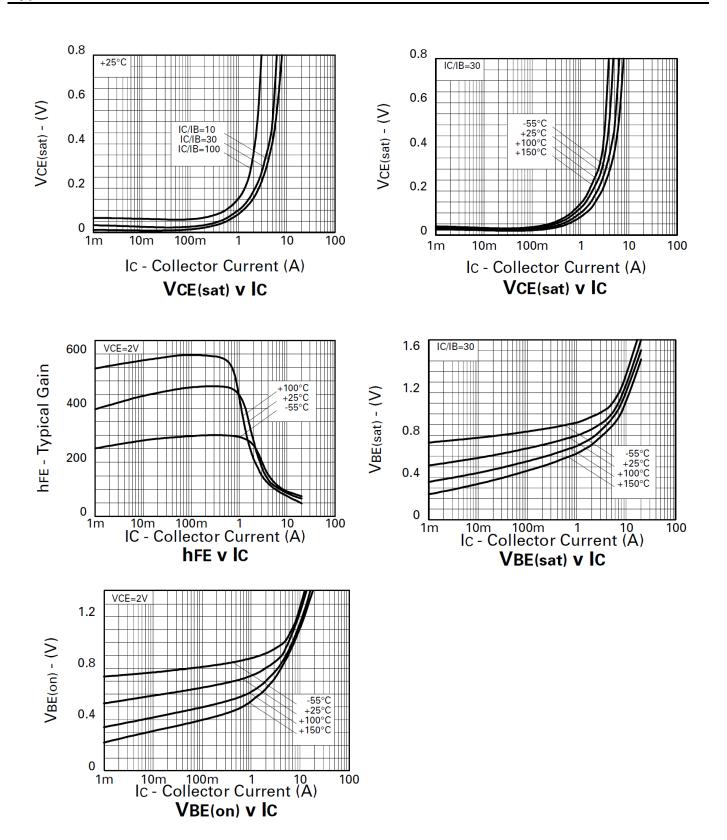
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	250	_	V	$I_{\rm C} = 100 \mu {\rm A}$	
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	150	250	_	V	I <sub>C</sub> = 100μA	
Collector-Emitter Breakdown Voltage (Note 12)	BV <sub>CEO</sub>	75	100	_	V	$I_{C} = 10 \text{mA}$	
Collector-Emitter Breakdown Voltage	BV <sub>CEV</sub>	150	250	_	V	$I_{C} = 100 \mu A, V_{EB} = 1 V$	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7.0	8.8	—	V	I <sub>E</sub> = 100μA	
Collector Cutoff Current	I <sub>CBO</sub>	_	0.9	10	nA	V <sub>CB</sub> = 120V	
Collector Cutoff Current	ICES	_	1.5	10	nA	V <sub>CES</sub> = 120V	
Emitter Cutoff Current	I <sub>EBO</sub>	_	0.3	10	nA	$V_{EB} = 4V$	
		270	440	_	_	$I_{C} = 10 \text{mA}, V_{CE} = 2 \text{V}$	
		300	450	1,200		$I_{C} = 0.5A, V_{CE} = 2V$	
DC Current Transfer Static Ratio (Note 12)	h <sub>FE</sub>	300	450	_		$I_{C} = 1A, V_{CE} = 2V$	
		40	60	_		$I_{C} = 4.5A, V_{CE} = 2V$	
			20	_		$I_{C} = 10A, V_{CE} = 2V$	
	V <sub>CE(sat)</sub>	_	21	30	mV	$I_{\rm C} = 0.2$ A, $I_{\rm B} = 20$ mA	
		_	55	75		$I_{C} = 0.5A, I_{B} = 20mA$	
Collector-Emitter Saturation Voltage (Note 12)		_	150	200		$I_{C} = 1A, I_{B} = 10mA$	
			160	210		$I_{\rm C} = 2A, I_{\rm B} = 100 {\rm mA}$	
		_	350	440		I <sub>C</sub> = 4.5A, I <sub>B</sub> = 200mA	
Base-Emitter Saturation Voltage (Note 12)	V <sub>BE(sat)</sub>	_	900	1,000	mV	$I_{\rm C} = 3A, I_{\rm B} = 100 {\rm mA}$	
Base-Emitter Turn-On Voltage (Note 12)	V <sub>BE(on)</sub>	_	825	950	mV	$I_C = 3A, V_{CE} = 2V$	
Transitional Frequency (Note 12)	f <sub>T</sub>	_	140	_	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}, $ f = 100MHz	
Output Capacitance	C <sub>obo</sub>	_	21	30	pF	V <sub>CB</sub> = 10V, f = 1MHz	
Queitabing Time	t <sub>on</sub>		162	_	ns	$V_{CC} = 50V, I_C = 2A,$	
Switching Time	t <sub>off</sub>	_	900	_	ns	$I_{B1} = I_{B2} = \pm 20 \text{mA}$	

Note: 12. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

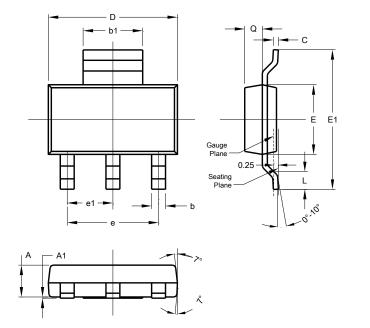




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

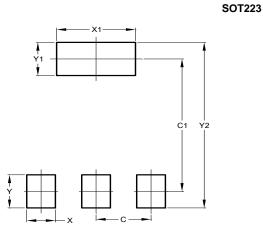
SOT223



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
q	0.84	0.94	0.89		
All I	All Dimensions in mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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